

IPW

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

Applicant: Schang-Jing Hon :
Serial No: 10/781,769 : Art Unit #2818
Filed: 20 February 2004 : Examiner:
Title: GALLIUM NITRIDE VERTICAL : D. Nhu
LIGHT EMITTING DIODE :
STRUCTURE AND METHOD OF :
SEPARATING A SUBSTRATE AND :
A THIN FILM IN THE STRUCTURE :

AMENDMENT

Honorable Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Responsive to the outstanding Official Action dated 13 June 2005, please
amend the above-referenced Patent Application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims are reflected in the Listing of Claims which
begins on page 4 of this paper.

Remarks/Arguments begin on page 7 of this paper.